

# Quadrature Silicon Photodiode – 5 mm active Area

#### Description

The QSP-TO-5 is a Silicon Quadrant photodiode with a 5 mm active area packaged in a hermetic TO package. The device offers high responsivity and balanced responsivity between the quadrants. Low cross talk between the quadrants makes the device suitable for detection applications.

#### Features

- Dark Current ~ 5 nA
- Spectral Noise Density ~ 5  $\frac{pA}{\sqrt{Hz}}$
- Terminal Capacitance 4.2 pF at VBR<sub>90%</sub>
- 15 M $\Omega$  Shunt resistance
- Balanced responsivity across quadrants



#### Applications

- Position Measurement
- Optical Guidance





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| Parameter              | Symbol          | Min. | Тур. | Max  | Unit                          | Notes                         |  |
|------------------------|-----------------|------|------|------|-------------------------------|-------------------------------|--|
| Breakdown Voltage      | V <sub>BR</sub> |      | 250  |      | V                             | ID = 100                      |  |
| Dark Current           | I <sub>D</sub>  |      | 5    |      | nA                            | Vr = 140                      |  |
| Terminal Capacitance   | Ct              |      | 4.2  |      | Pf                            | Taken at 90% VBR at f = 1 MHz |  |
| Responsivity           | R               |      | 0.5  |      | A/W                           | λ = 850 nm , M = 1            |  |
|                        |                 |      | 0.6  |      |                               | $\lambda$ = 1064 nm , M = 1   |  |
| Active Area            | A <sub>PD</sub> |      | 22   |      | mm²                           | Photodiode area               |  |
| Gap                    | D               |      | 70   |      | um                            | Between quadrants             |  |
| Spectral Range         | λ               | 400  |      | 1100 | nm                            |                               |  |
| Cross Talk             |                 | 1    |      |      | %                             |                               |  |
| Rise Time              | t <sub>r</sub>  |      | 12   |      | ns                            | 10% - 90%                     |  |
| Shunt Resistance       | Rs              |      | 15   |      | MΩ                            | Between two quadrants         |  |
| Spectral Noise Density | SN              |      | 5    |      | $\frac{pA}{\sqrt{\text{Hz}}}$ | Vr = 140                      |  |

# Electro-Optical Characteristics ( $T_{op} 23 \pm 3^{\circ}c$ , unless otherwise specified)

#### **Absolute Maximum Ratings**

| Parameter                       | Symbol           | Condition | Min. | Max. | Unit              |
|---------------------------------|------------------|-----------|------|------|-------------------|
| Reverse Voltage                 | Vr               |           |      | 150  | V                 |
| Saturated Incident Intensity    | $P_{sat}$        |           |      | 0.3  | W/cm <sup>2</sup> |
| Reverse Current                 | I <sub>R</sub>   |           |      | 0.5  | mA                |
| Storage Temperature             | T <sub>stg</sub> |           | -55  | 120  | °C                |
| Storage Humidity                | $H_{stg}$        |           |      | 85   | % r.H.            |
| Operating Temperature           | T <sub>op</sub>  |           | -40  | 105  | °C                |
| Soldering Temperature           | T <sub>st</sub>  | 10 sec    |      | 260  | °C                |
| ESD Susceptibility <sup>1</sup> |                  | HBM       |      | 500  | V                 |

Operating at maximum ratings for a prolonged period will cause damage to the device.

<sup>1</sup> ESD Sensitive device. Proper ESD procedures must be followed





Typical Increase in responsivity as a function of photodiode temperature



Data taken between -40 °C and 60°C at 10°C increments. Data was interpolated to fill in data points.



# Spectral response (T<sub>op</sub> 23 ± 3°c)

Function

No Connect

Cathode (-)



## Device Dimensions (all units in mm) and Pin Configuration



### **Inquiry Information**

Sales: All inquiries regarding sales please contact <a href="mailto:Sales@NuPhotonics.com">Sales@NuPhotonics.com</a>

General: If you are interested in a custom solution, general information, or engineering related information please contact Inquiry@NuPhotonics.com



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